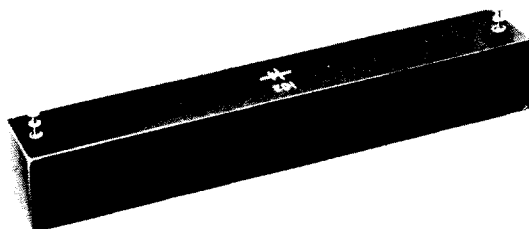


KILOVOLT RECTIFIER ASSEMBLIES

- MATCHED SILICON RECTIFIER ELEMENTS
- RATED CURRENT TO 1.0 AMPERE
- PRV 5,000 TO 50,000 VOLTS
- FAST RECOVERY (RVP SERIES)
- ALL APPLICABLE MIL-STD-750 TESTS
- HIGH THERMAL CONDUCTIVITY ENCAPSULATION



EDI Type No.	Peak Reverse Voltage PRV (Volts)	Avg. Fwd. Current, I_o at 25°C (Amps)	Max. Fwd. Voltage Drop at 25°C and I_o V_F (Volts)	Dimension "L" Inches Fig. 3
STANDARD RECOVERY				
KVP5	5,000	1.00	8	2.5
KVP6	6,000	1.00	9	2.5
KVP7	7,000	1.00	10	3.0
KVP8	8,000	1.00	11	3.0
KVP9	9,000	1.00	14	3.0
KVP10	10,000	1.00	15	3.5
KVP15	15,000	1.00	21	5.0
KVP20	20,000	.75	26	5.5
KVP25	25,000	.75	32	6.0
KVP30	30,000	.75	39	6.0
KVP35	35,000	.75	46	6.5
KVP40	40,000	.75	53	6.5
KVP50	50,000	.75	65	7.0
300 NANOSECOND RECOVERY (FIG. 4)				
RVP5	5,000	.90	10	2.5
RVP6	6,000	.90	11	2.5
RVP7	7,000	.90	12	3.0
RVP8	8,000	.90	13	3.0
RVP9	9,000	.90	16	3.0
RVP10	10,000	.90	17	3.5
RVP15	15,000	.90	25	5.0
RVP20	20,000	.70	30	5.5
RVP25	25,000	.70	36	6.0
RVP30	30,000	.70	43	6.0
RVP35	35,000	.70	50	6.5
RVP40	40,000	.70	58	6.5
RVP50	50,000	.70	72	7.0

ELECTRICAL CHARACTERISTICS at $T_A = 25^\circ\text{C}$ Unless Otherwise Specified	KVP SERIES STANDARD RECOVERY
Max. DC Reverse Current @PRV and 25°C, I_R	5 μA
Max. DC Reverse Current @PRV and 100°C, I_R	100 μA
Ambient Operating Temperature Range, T_A	-55°C to +150°C
Storage Temperature Range, T_{STG}	-55°C to +150°C
Max. One-Half Cycle Surge Current, I_{FM} (Surge) @ 60 Hz	50 Amps
Forward Current Repetitive Peak, I_{FRM}	10 Amps

ELECTRICAL CHARACTERISTICS at $T_A = 25^\circ\text{C}$ Unless Otherwise Specified	RVP SERIES FAST RECOVERY
Max. DC Reverse Current @PRV and 25°C, I_R	5 μA
Max. DC Reverse Current @PRV and 100°C, I_R	250 μA
Max. Reverse Recovery Time, t_{rr} (Fig. 4)	300 nanosec
Ambient Operating Temperature Range, T_A	-55°C to +150°C
Storage Temperature Range, T_{STG}	-55°C to +150°C
Max. One-Half Cycle Surge Current, I_{FM} (Surge) @ 60 Hz	30 Amps
Forward Current Repetitive Peak, I_{FRM}	8 Amps



ELECTRONIC DEVICES, INC.

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FIG. 1

OUTPUT CURRENT vs AMBIENT TEMPERATURE

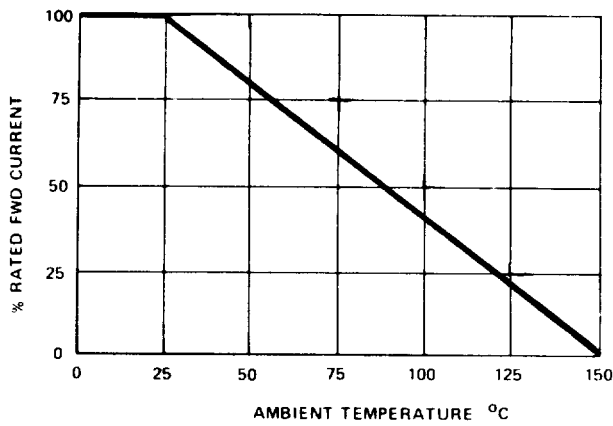


FIG. 2

NON-REPETITIVE SURGE CURRENT RATINGS

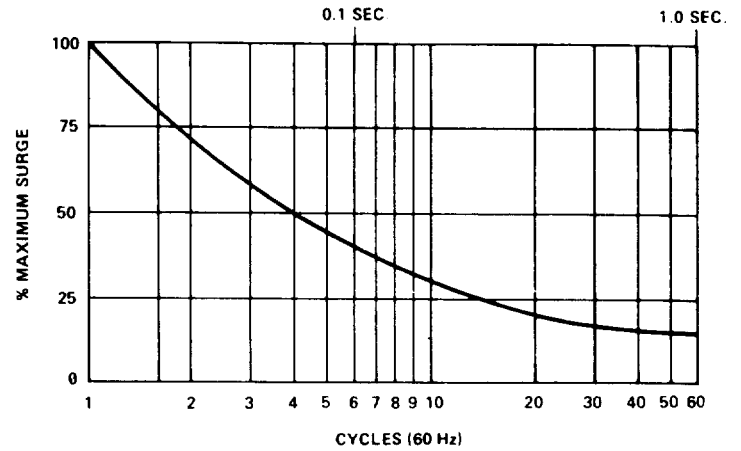
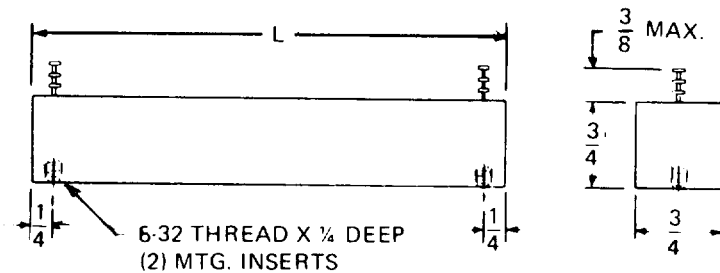


FIG. 3

CASE OUTLINE



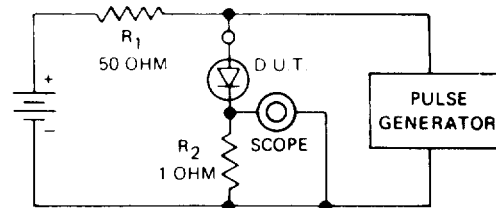
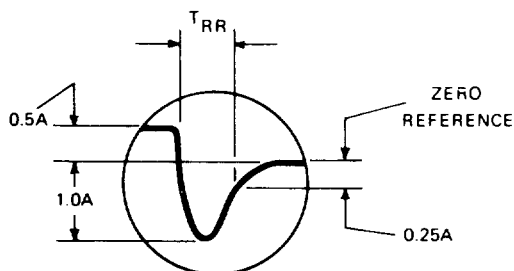
(ALL DIMENSIONS IN INCHES)

It is recommended that a proper heat sink be used on the terminals of this device between the body and the soldering point to prevent damage from excess heat.

TEST CIRCUIT

FIG. 4

TYPICAL REVERSE RECOVERY WAVEFORM



R_1 , R_2 NON-INDUCTIVE RESISTORS
PULSE GENERATOR — HEWLETT PACKARD 214A OR EQUIV.
1KC REP. RATE, 10 μ SEC. PULSE WIDTH
ADJUST PULSE AMPLITUDE FOR PEAK I_R